

FEATURES

- **LOW C X R:**
C X R = 11 pF · Ω
- **LOW OUTPUT CAPACITANCE:**
C_{OUT} = 1.1 pF TYP
- **1 CHANNEL TYPE:**
(1a output)
- **DESIGNED FOR AC/DC SWITCHING LINE CHANGER**
- **SMALL AND THIN PACKAGE:**
4 pin SOP, Height = 2.1 mm
- **HIGH ISOLATION VOLTAGE:**
BV = 1500 Vr.m.s.
- **LOW OFFSET VOLTAGE**
- **AVAILABLE ON TAPE AND REEL:**
PS7200R-1A-E3, E4, F3, F4

DESCRIPTION

NEC's PS7200R-1A is a low output capacitance solid state relay containing a GaAs LED on the light emitting side (input side) and MOS FETs on the output side.

It is suitable for high-frequency signal control, due to its low C x R, low output capacitance, and low off-state leakage current.

APPLICATIONS

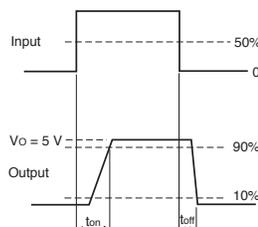
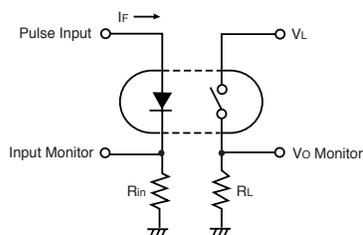
- **MEASUREMENT EQUIPMENT**

ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

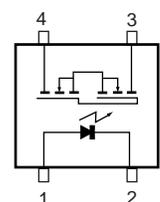
		PART NUMBER	PS7200R-1A			
	SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
Diode	V _F	Forward Voltage, I _F = 10 mA	V		1.2	1.4
	I _R	Reverse Current, V _R = 5 V	μA			5.0
MOS FET	I _{LOFF}	Off-State Leakage Current, V _D = 40 V	nA			10
	C _{OUT}	Output Capacitance, V = 0 V, f = 1 MHz	pF		1.1	
Coupled	I _{Fon}	LED On-state Current, I _L = 120 mA	mA			2.0
	R _{ON} ¹	On-State Resistance, I _F = 10 mA, I _L = 10 mA	Ω		10	12.5
	R _{ON} ²		Ω		11	14
	t _{ON}	Turn-on Time, I _F = 10 mA, V _O = 5 V, R _L = 500 Ω, PW ≥ 10 ms	ms		0.03	0.5
	t _{OFF}	Turn-off Time, I _F = 10 mA, V _O = 5 V, R _L = 500 Ω, PW ≥ 10 ms	ms		0.3	1.0
	R _{I-O}	Isolation Resistance, V _{I-O} = 1.0 kV _{DC}	Ω	10 ⁹		
	C _{I-O}	Isolation Capacitance, V = 0 V, f = 1 MHz	pF		0.3	

Notes:

1. Test Circuit for Switching Time:



PS7200R-1A



2. The turn-on time and turn-off time are specified as input-pulse width ≥ 10 ms. Be aware that when the device operates with an input-pulse width of under 10 ms, the turn-on time and turn-off time will increase.

PS7200R-1A

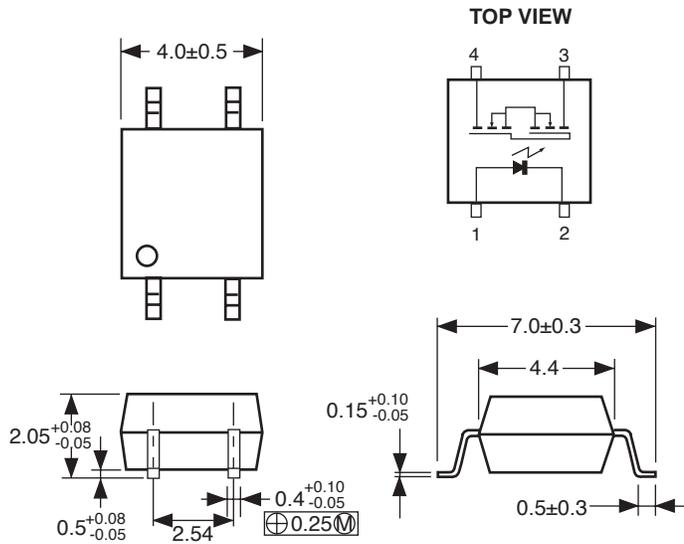
ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Diode			
I _F	Forward Current (DC)	mA	50
V _R	Reverse Voltage	V	5.0
P _D	Power Dissipation	mW	50
I _{FP}	Peak Forward Current ²	A	1
MOS FET			
V _L	Break Down Voltage	V	40
I _L	Continuous Load Current	mA	120
I _{LP}	Pulse Load Current ³ (AC/DC Connection)	mA	240
P _D	Power Dissipation	mW	200
Coupled			
BV	Isolation Voltage ⁴	Vr.m.s.	1500
P _T	Total Power Dissipation	mW	250
T _A	Operating Ambient Temp.	°C	-40 to +85
T _{STG}	Storage Temperature	°C	-40 to +100

Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. PW = 100 μs, Duty Cycle = 1 %.
3. PW = 100 ms, 1 shot.
4. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output.

OUTLINE DIMENSIONS (Units in mm)

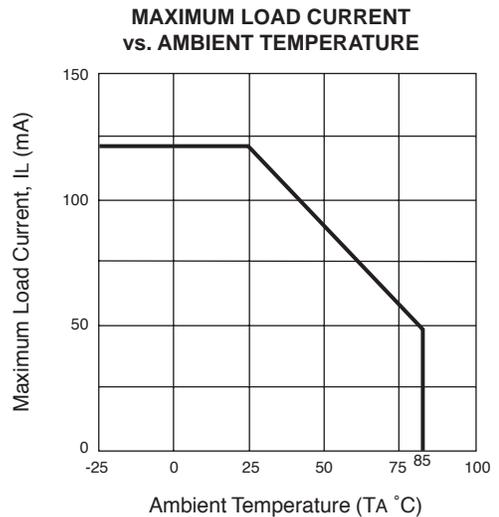
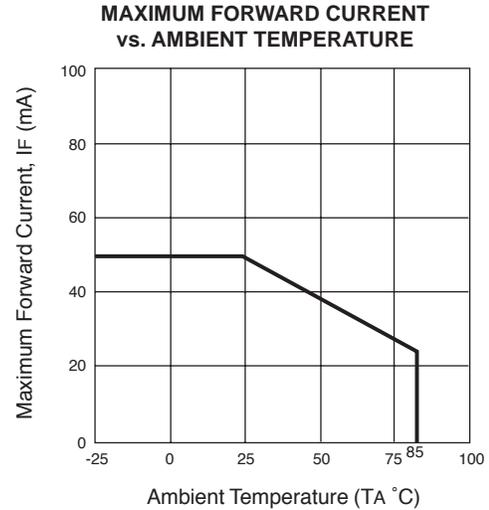


1. LED Anode
2. LED Cathode
3. MOSFET
4. MOSFET

RECOMMENDED OPERATING CONDITIONS (T_A = 25°C)

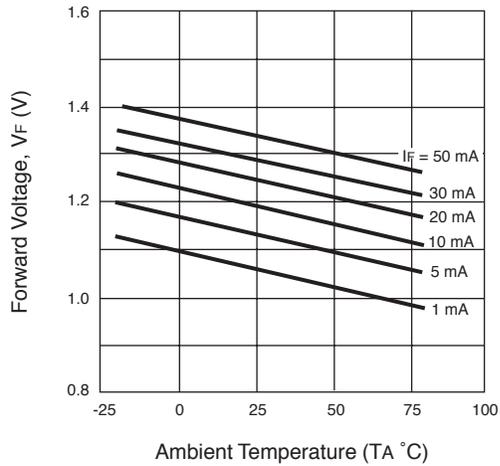
PART NUMBER		PS7200R-1A			
SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
I _F	LED Operating Current	mA	2	10	20
V _F	LED Off Voltage	V	0		0.5

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

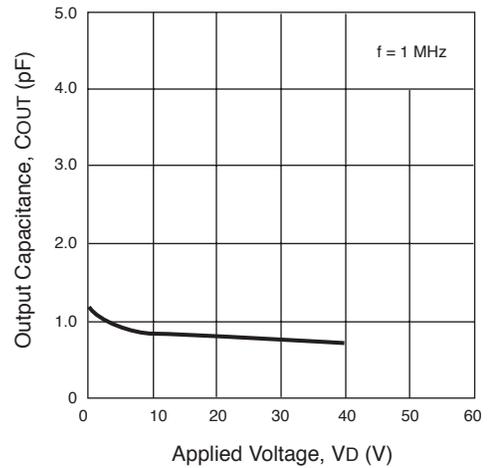


TYPICAL PERFORMANCE CURVES (TA = 25°C)

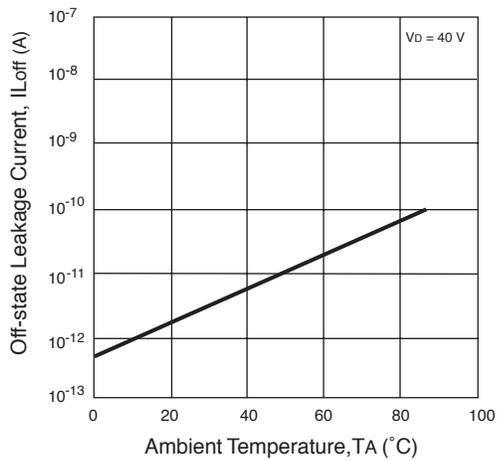
FORWARD VOLTAGE vs. AMBIENT TEMPERATURE



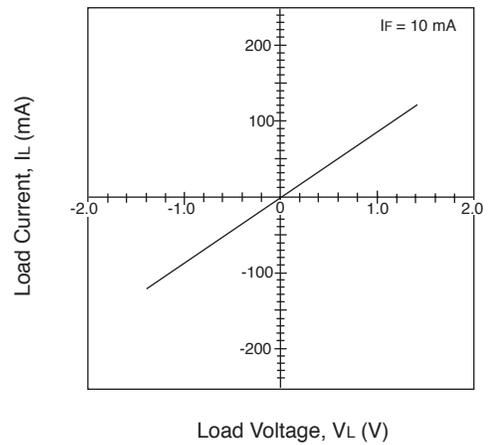
OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



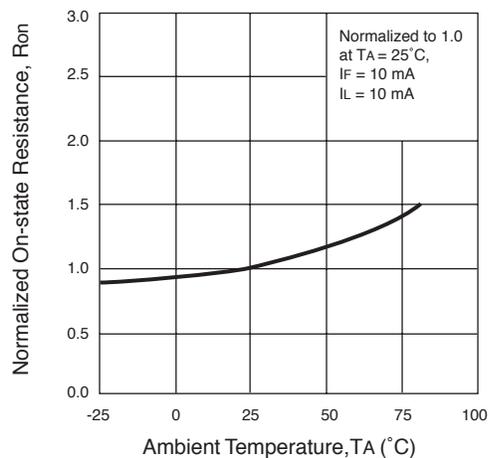
OFF-STATE LEAKAGE CURRENT vs. AMBIENT TEMPERATURE



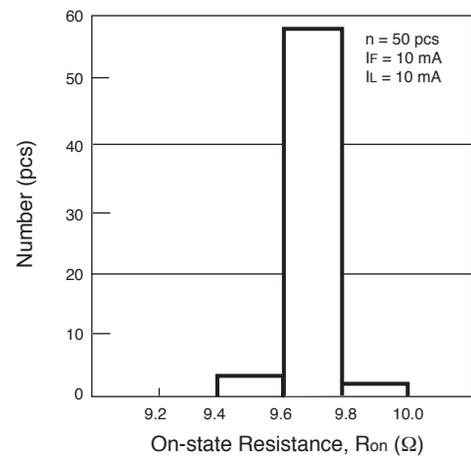
LOAD CURRENT vs. LOAD VOLTAGE



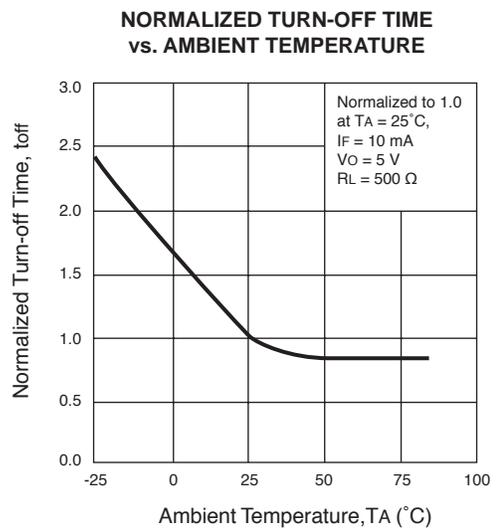
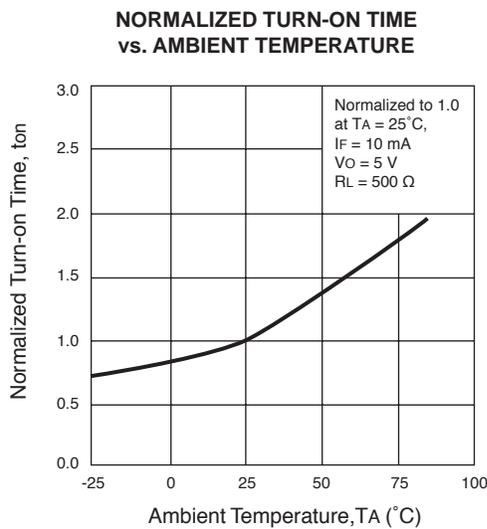
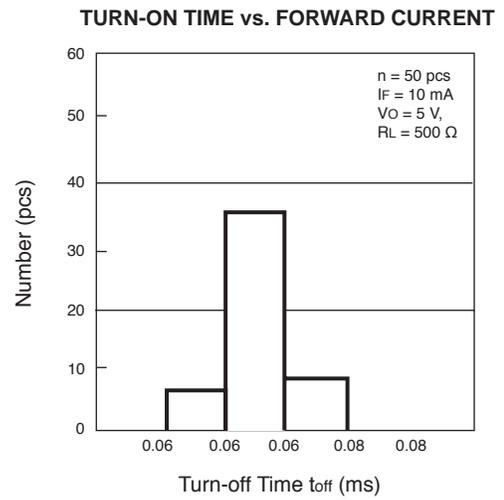
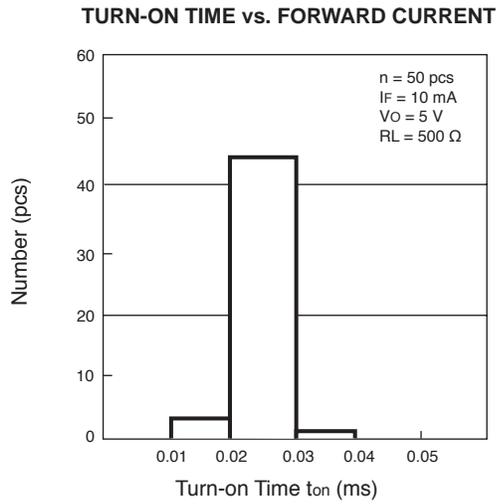
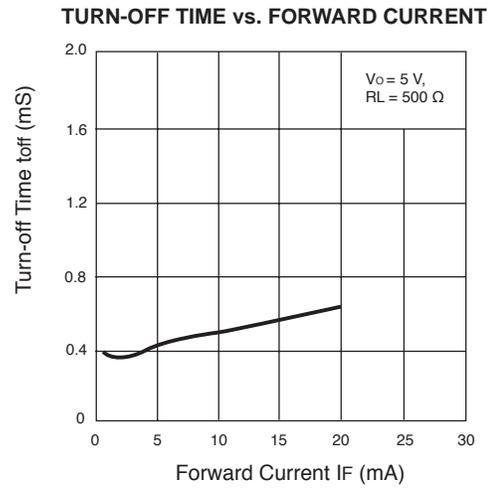
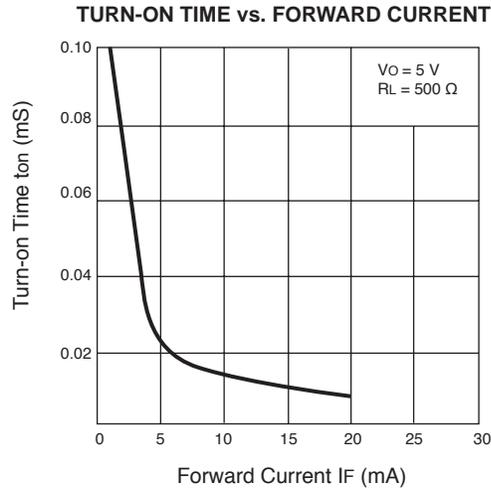
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



ON-STATE RESISTANCE DISTRIBUTION

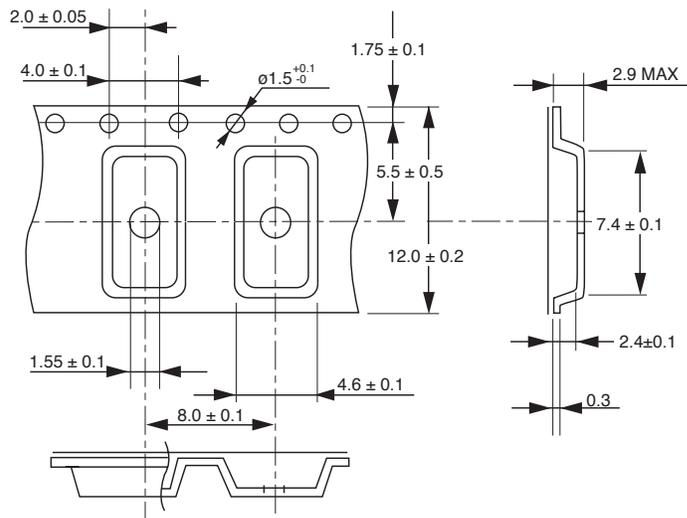


TYPICAL PERFORMANCE CURVES (TA = 25°C)



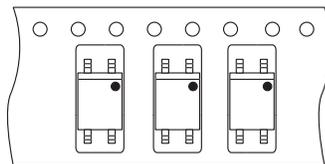
TAPING SPECIFICATIONS (Units in mm)

Tape Outline and Dimensions

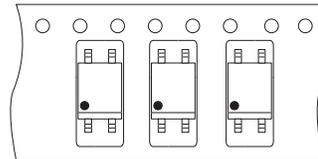


Tape Direction

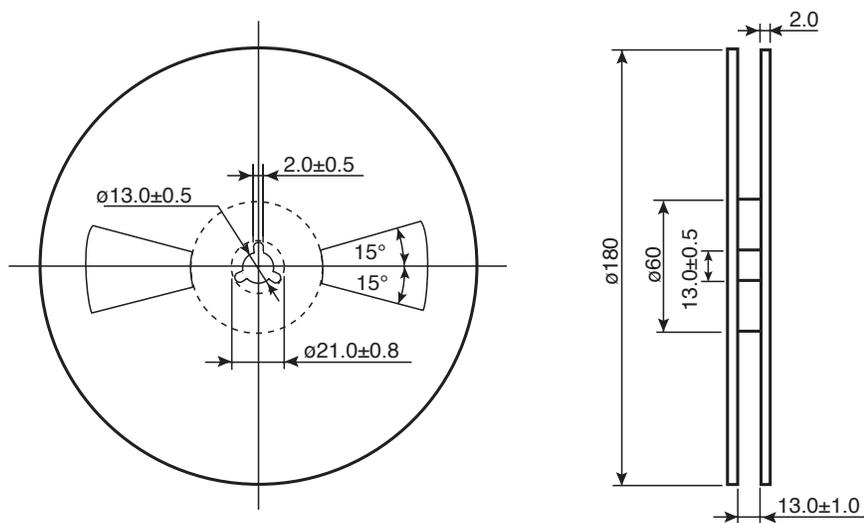
PS7200R-1A-E3



PS7200R-1A-E4



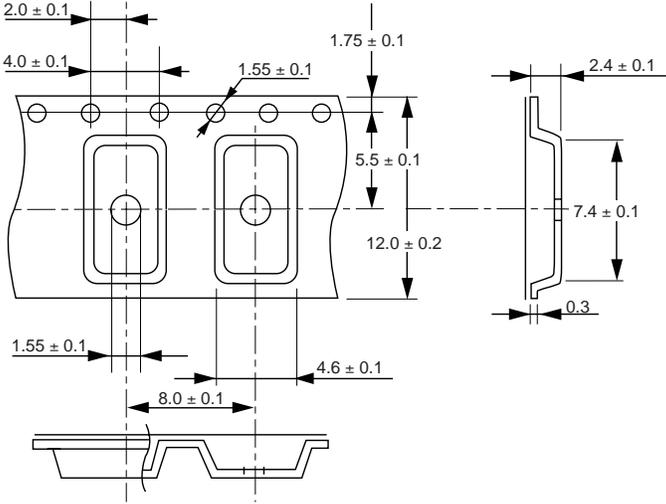
Reel Outline and Dimensions



Packing: 900 pcs/reel

TAPING SPECIFICATIONS (Units in mm)

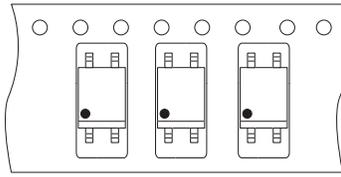
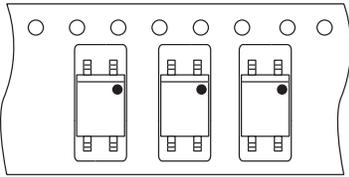
Tape Outline and Dimensions



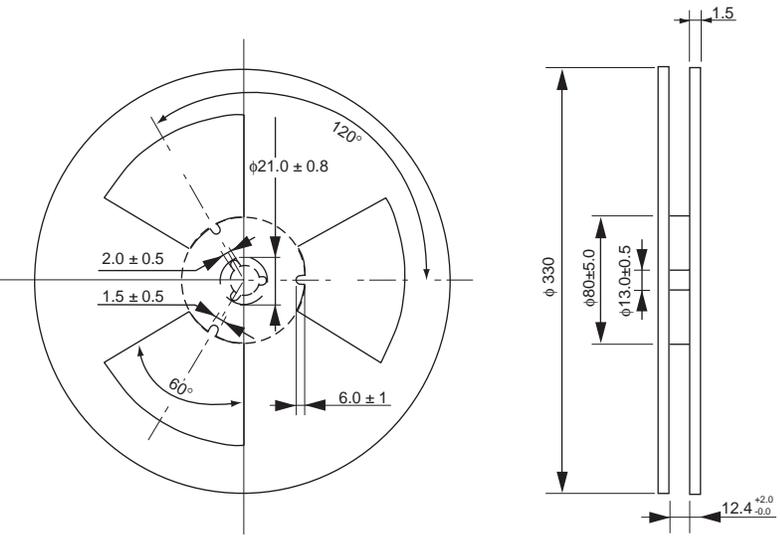
Tape Direction

PS7200R-1A-F3

PS7200R-1A-F4



Reel Outline and Dimensions

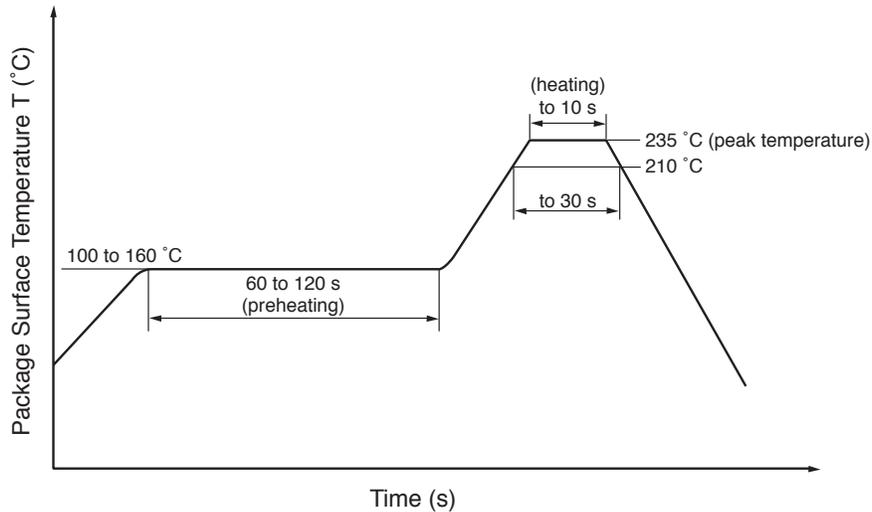


RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

- Peak reflow temperature 235 °C or below (package surface temperature)
- Time of temperature higher than 210 °C 30 seconds or less
- Number of reflows Two
- Flux Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 100°C or below (package surface temperature)
- Number of times One
- Flux Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

- Fluxes Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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